Monday Morning, November 7, 2022

Nanoscale Science and Technology Division Room 304 - Session NS3+EM+TF-MoM

Nanophotonics, Metasurfaces and Plasmonic Systems Including Inverse Design Methods

Moderators: David Czaplewski, Argonne National Laboratory, Nikolai Klimov, National Institute of Standards and Technology

11:20am NS3+EM+TF-MoM-10 Quantum and Nonlinear Photonics in Silicon Carbide with Inverse Design, Daniil Lukin, J. Vuckovic, Stanford University INVITED

Integrated photonics technology has achieved the degree of scalability and complexity needed for building up photonic quantum computers based on optically-addressable spin qubits such as color centers. However, at present none of the industry-standard photonics materials host high quality color centers. Silicon Carbide has the potential to become a technologically-mature platform that can close this longstanding gap between classical and quantum photonics devices. I will discuss the recent progress of Silicon Carbide integrated photonics for quantum and nonlinear applications, as well as the applications of inverse-design for novel photonics functionalities.

Author Index

Bold page numbers indicate presenter -v-

— L — Lukin, D.: NS3+EM+TF-MoM-10, **1**

Vuckovic, J.: NS3+EM+TF-MoM-10, 1